

photodiodes



Silicon Avalanche Photodiodes

- Hermetically Sealed Packages

Si APD—Standard Types—400 nm to 1100 nm

Technical Specification

Part Number	Standard Package	Photo Sens. Diam. mm	Resp. @900 nm A/W	Dark Curr. Id (nA)	Spect. Noise Curr. Dens. In (pA/√Hz)	Cap. @100 kHz Cd (pF)	Resp. Time tr (ns)	NEP @ 900 nm fW/√Hz	VOP Range V
C30817E	TO-5	0.8	75	50	0.5	2	2	7	275-425
C30872E	TO-8	3	45	100	0.5	10	2	11	275-425
C30902E	TO-18	0.5	77 (@ 830 nm)	15	0.23	1.6	0.05	3 (@ 830 nm)	180-250
C30902S	TO-18	0.5	128 (@ 830 nm)	15	0.11	1.6	0.05	0.86 (@ 830 nm)	180-250
C30916E	TO-5	1.5	70	100	0.5	3	2	8	275-425

Test conditions: T = 22°C

Si APD—Arrays Quadrant and Linear—400 nm to 1100 nm

Technical Specification

Part Number	Standard Package	Photo Sens. Diam. mm	Resp. @830 nm A/W	Dark Curr. Id (nA)	Spect. Noise Curr. Dens. In (pA/√Hz)	Cap. @100 kHz Cd (pF)	Resp. Time tr (ns)	NEP @ 830 nm fW/√Hz	VOP Range V
C30927E-01	TO-8	1.5 total	62 (@900 nm)	25	0.25	1	3	16 (@900 nm)	275-425
C30927E-02	TO-8	1.5 total	62 (@900 nm)	25	0.25	1	3	16 (@900 nm)	275-425
C30927E-03	TO-8	1.5 total	62 (@900 nm)	25	0.25	1	3	16 (@900 nm)	275-425
C30985E	Custom	0.3 pitch	31	1	0.1	0.5	2	3	250-425

Test conditions: T = 22°C

Si APD—Low Cost, High Volume—400 nm to 1000 nm

Technical Specification

Part Number	Standard Package	Photo Sens. Diam. mm	Resp. @900 nm A/W	Dark Curr. Id (nA)	Spect. Noise Curr. Dens. In (pA/√Hz)	Cap. @100 kHz Cd (pF)	Resp. Time tr (ns)	NEP @ 900 nm fW/√Hz	VOP Range V
C30724E	TO-18	0.5	9 (@ M=15)	25	0.1	1	5	11	120-200
C30724P	Plastic	0.5	9 (@ M=15)	25	0.1	1	5	11	120-200
C30737E	TO-18	0.5	47 (@ I=800 nm M=100)	20	0.3	2.5	0.3	6.4 (@ 800 nm M=100)	120-200

Test conditions: T = 22°C

Si APD—TE-Cooled

Technical Specification

Part Number	Standard Package	Photo Sens. Diam. mm	Resp. @830 nm A/W	Dark Curr. Id (nA)	Spect. Noise Curr. Dens. In (pA/√Hz)	Cap. @100 kHz Cd (pF)	Resp. Time tr (ns)	NEP @ 830 nm fW/√Hz	ADP VOP Range V
C30902S-TC	TO-66	0.5	128	2	0.04	1.6	0.5	0.3	160-250
C30902S-DTC	TO-66	0.5	128	1	0.02	1.6	0.5	0.16	160-250

Test conditions: T = 0°C for -TC and -20°C for -DTC

ADP VOP Range: temperature dependent